

# CMOS Micropower Step-Up Switching Regulator

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage ..... 18V  
 Storage Temperature Range ..... -65°C to +160°C  
 Lead Temperature (soldering, 10s) ..... +300°C  
 Operating Temperature Range  
   MAX630C, MAX4193C ..... 0°C to +70°C  
   MAX630E, MAX4193E ..... -40°C to +85°C  
   MAX630M, MAX4193M ..... -55°C to +125°C

Power Dissipation  
   8-Pin PDIP (derate 6.25mW/°C above +50°C) ..... 468mW  
   8-Pin SO (derate 5.88mW/°C above +50°C) ..... 441mW  
   8-Pin CERDIP (derate 8.33mW/°C above +50°C) ..... 833mW  
 Input Voltage (Pins 1, 2, 6, 7) ..... -0.3V to (+V<sub>S</sub> + 0.3V)  
 Output Voltage, L<sub>X</sub> and LBD ..... 18V  
 L<sub>X</sub> Output Current ..... 525mA (Peak)  
 LBD Output Current ..... 50mA

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

(+V<sub>S</sub> = +6.0V, T<sub>A</sub> = +25°C, I<sub>C</sub> = 5.0μA, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX630			MAX4193			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Supply Voltage	+V <sub>S</sub>	Operating	2.0		16.5	2.4		16.5	V
		Startup	1.9						
Internal Reference Voltage	V <sub>REF</sub>		1.29	1.31	1.33	1.24	1.31	1.38	V
Switch Current	I <sub>SW</sub>	V <sub>3</sub> = 400mV	75	150		75	150		mA
Supply Current (at Pin 5)	I <sub>S</sub>	I <sub>3</sub> = 0mA		70	125		90		μA
Efficiency				85			85		%
Line Regulation		0.5V <sub>0</sub> < V <sub>S</sub> < V <sub>0</sub> (Note 1)		0.08	0.2		0.06	0.5	% V <sub>OUT</sub>
Load Regulation		V <sub>S</sub> = +5V, P <sub>LOAD</sub> = 0 to 150mW (Note 1)		0.2	0.5		0.2	0.5	% V <sub>OUT</sub>
Operating Frequency Range	F <sub>O</sub>	(Note 2)	0.1	40	75	0.1	25	75	kHz
Reference Set Internal Pulldown Resistance	R <sub>IC</sub>	V <sub>6</sub> = V <sub>S</sub>	0.5	1.5	10	0.5	1.5	10	MΩ
Reference Set Input Voltage Threshold	V <sub>IC</sub>		0.2	0.8	1.3	0.2	0.8	1.3	V
Switch Current	I <sub>SW</sub>	V <sub>3</sub> = 1.0V	100			100			mA
Switch Leakage Current	I <sub>CO</sub>	V <sub>3</sub> = 16.5V		0.01	1.0		0.01	5.0	μA
Supply Current (Shutdown)	I <sub>SO</sub>	I <sub>C</sub> < 0.01μA		0.01	1.0		0.01	5.0	μA
Low-Battery Bias Current	I <sub>LBR</sub>			0.01	10		0.01	10	nA
Capacitor Charging Current	I <sub>CX</sub>			30			30		μA
C <sub>X+</sub> Threshold Voltage				+V <sub>S</sub> - 0.1			+V <sub>S</sub> - 0.1		V
C <sub>X-</sub> Threshold Voltage				0.1			0.1		V
V <sub>FB</sub> Input Bias Current	I <sub>FB</sub>			0.01	10		0.01	10	nA
Low-Battery Detector Output Current	I <sub>LBD</sub>	V <sub>8</sub> = 0.4V, V <sub>1</sub> = 1.1V	250	600		250	600		μA
Low-Battery Detector Output Leakage	I <sub>LBDO</sub>	V <sub>8</sub> = 16.5V, V <sub>1</sub> = 1.4V		0.01	5.0		0.01	5.0	μA

# CMOS Micropower Step-Up Switching Regulator

MAX630/MAX4193

## ELECTRICAL CHARACTERISTICS

( $+V_S = +6.0V$ ,  $T_A =$  Full Operating Temperature Range,  $I_C = 5.0\mu A$ , unless otherwise noted.)

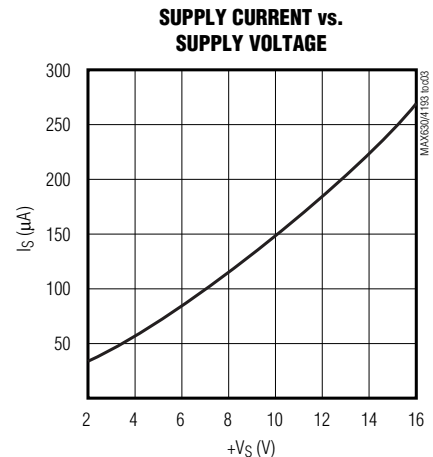
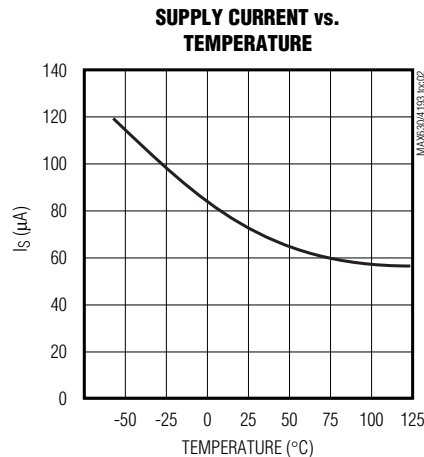
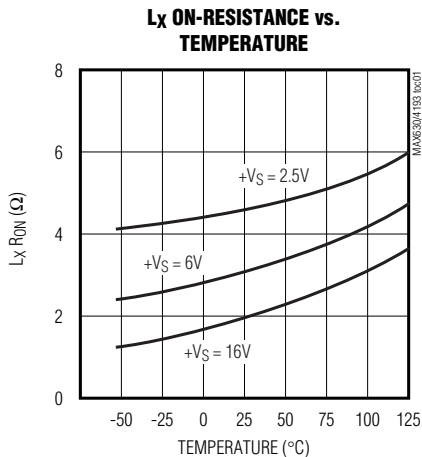
PARAMETER	SYMBOL	CONDITIONS		MAX630			MAX4193			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
Supply Voltage	+V <sub>S</sub>			2.2		16.5	3.5		16.5	V
Internal Reference Voltage	V <sub>REF</sub>			1.25	1.31	1.37	1.20	1.31	1.42	V
Supply Current (Pin 5)	I <sub>S</sub>	I <sub>3</sub> = 0mA			70	200		90	300	μA
Line Regulation		0.5V <sub>OUT</sub> < V <sub>S</sub> < V <sub>OUT</sub> (Note 1)			0.2	0.5		0.5	1.0	% V <sub>OUT</sub>
Load Regulation		V <sub>S</sub> = 0.5V <sub>0</sub> , P <sub>L</sub> = 0 to 150mW (Note 1)			0.5	1.0		0.5	1.0	% V <sub>OUT</sub>
Reference Set Internal Pulldown Resistance	R <sub>IC</sub>	V <sub>6</sub> = V <sub>S</sub>	0°C ≤ T <sub>A</sub> ≤ +70°C	0.45	1.5	10	0.45	1.5	10	MΩ
			-40°C ≤ T <sub>A</sub> ≤ +85°C	0.4	1.5	10	0.4	1.5	10	
			-55°C ≤ T <sub>A</sub> ≤ +125°C	0.3	1.5	10	0.3	1.5	10	
Reference Set Input Voltage Threshold	V <sub>IC</sub>			0.2	0.8	1.3	0.2	0.8	1.3	V
Switch Leakage Current	I <sub>CO</sub>	V <sub>3</sub> = 16.5V			0.1	30		0.1	30	μA
Supply Current (Shutdown)	I <sub>SO</sub>	I <sub>C</sub> < 0.01μA			0.01	10		0.01	30	μA
Low-Battery Detector Output Current	I <sub>LBD</sub>	V <sub>8</sub> = 0.4V, V <sub>1</sub> = 1.1V		250	600		250	600		μA

**Note 1:** Guaranteed by correlation with DC pulse measurements.

**Note 2:** The operating frequency range is guaranteed by design and verified with sample testing.

## Typical Operating Characteristics

( $T_A = +25^\circ C$ , unless otherwise noted.)



# CMOS Micropower Step-Up Switching Regulator

## Pin Description

PIN	NAME	FUNCTION
1	LBR	Low-Battery Detection Comparator Input. The LBD output, pin 8, sinks current whenever this pin is below the low-battery detector threshold, typically 1.31V.
2	C <sub>X</sub>	An external capacitor connected between this terminal and ground sets the oscillator frequency. 47pF = 40 kHz.
3	L <sub>X</sub>	This pin drives the external inductor. The internal N-channel MOSFET that drives L <sub>X</sub> has an output resistance of 4Ω and a peak current rating of 525mA.
4	GND	Ground
5	+V <sub>S</sub>	The positive supply voltage, from 2.0V to 16.5V (MAX630).
6	I <sub>C</sub>	The MAX630/MAX4193 shut down when this pin is left floating or is driven below 0.2V. For normal operation, connect I <sub>C</sub> directly to +V <sub>S</sub> or drive it high with either a CMOS gate or pullup resistor connected to +V <sub>S</sub> . The supply current is typically 10nA in the shutdown mode
7	V <sub>FB</sub>	The output voltage is set by an external resistive divider connected from the converter output to V <sub>FB</sub> and ground. The MAX630/MAX4193 pulse the L <sub>X</sub> output whenever the voltage at this terminal is less than 1.31V.
8	LBD	The Low-Battery Detector output is an open-drain N-channel MOSFET that sinks up to 600μA (typ) whenever the LBR input, pin 1, is below 1.31V.

## Detailed Description

The operation of the MAX630 can best be understood by examining the voltage regulating loop of Figure 1. R1 and R2 divide the output voltage, which is compared with the 1.3V internal reference by comparator COMP1. When the output voltage is lower than desired, the comparator output goes high and the oscillator output pulses are passed through the NOR gate latch, turning on the output N-channel MOSFET at pin 3, L<sub>X</sub>. As long as the output voltage is less than the desired voltage, pin 3 drives the inductor with a series of pulses at the oscillator frequency.

Each time the output N-channel MOSFET is turned on, the current through the external coil, L1, increases, storing energy in the coil. Each time the output turns off, the voltage across the coil reverses sign and the voltage at L<sub>X</sub> rises until the catch diode, D1, is forward biased, delivering power to the output.

When the output voltage reaches the desired level,  $1.31V \times (1 + R1 / R2)$ , the comparator output goes low and the inductor is no longer pulsed. Current is then supplied by the filter capacitor, C1, until the output voltage drops below the threshold, and once again L<sub>X</sub> is switched on, repeating the cycle. The average duty cycle at L<sub>X</sub> is directly proportional to the output current.

## Output Driver (L<sub>X</sub> Pin)

The MAX630/MAX4193 output device is a large N-channel MOSFET with an on-resistance of 4Ω and a peak current rating of 525mA. One well-known advantage that MOSFETs have over bipolar transistors in switching applications is higher speed, which reduces switching losses and allows the use of smaller, lighter, less costly magnetic components. Also important is that MOSFETs, unlike bipolar transistors, do not require base current that, in low-power DC-DC converters, often accounts for a major portion of input power.

The operating current of the MAX630 and MAX4193 increases by approximately 1μA/kHz at maximum power output due to the charging current required by the gate capacitance of the L<sub>X</sub> output driver (e.g., 40μA increase at a 40kHz operating frequency). In comparison, equivalent bipolar circuits typically drive their NPN L<sub>X</sub> output device with 2mA of base drive, causing the bipolar circuit's operating current to increase by a factor of 10 between no load and full load.

## Oscillator

The oscillator frequency is set by a single external, low-cost ceramic capacitor connected to pin 2, C<sub>X</sub>. 47pF sets the oscillator to 40kHz, a reasonable compromise between lower switching losses at low frequencies and reduced inductor size at higher frequencies.

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MAX630/MAX4193

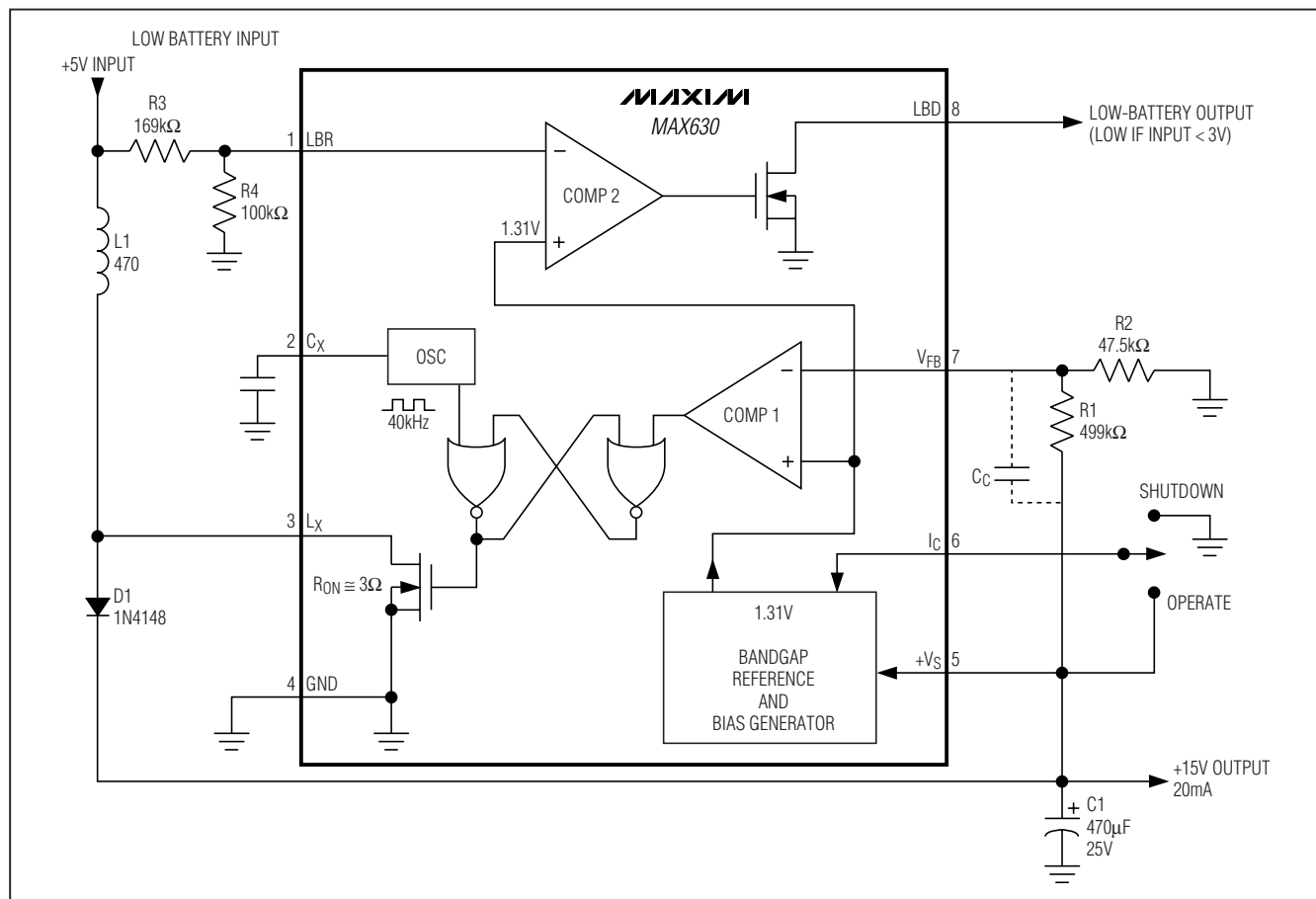


Figure 1. +5V to +15V Converter and Block Diagram

## Low-Battery Detector

The low-battery detector compares the voltage on LBR with the internal 1.31V reference. The output, LBD, is an open-drain N-channel MOSFET. In addition to detecting and warning of a low battery voltage, the comparator can also perform other voltage-monitoring operations such as power-failure detection.

Another use of the low-battery detector is to lower the oscillator frequency when the input voltage goes below a specified level. Lowering the oscillator frequency increases the available output power, compensating for the decrease in available power caused by reduced input voltage (see Figure 5).

## Logic-Level Shutdown Input

The shutdown mode is entered whenever IC (pin 6) is driven below 0.2V or left floating. When shut down, the

MAX630's analog circuitry, oscillator, LX, and LBD outputs are turned off. The device's quiescent current during shutdown is typically 10nA (1μA max).

## Bootstrapped Operation

In most circuits, the preferred source of +VS voltage for the MAX630 and MAX4193 is the boosted output voltage. This is often referred to as a "bootstrapped" operation since the circuit figuratively "lifts" itself up.

The on-resistance of the N-channel LX output decreases with an increase in +VS; however, the device operating current goes up with +VS (see the *Typical Operating Characteristics*, IS vs. +VS graph). In circuits with very low output current and input voltages greater than 3V, it may be more efficient to connect +VS directly to the input voltage rather than bootstrap.

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## External Components

### Resistors

Since the LBR and  $V_{FB}$  input bias currents are specified as 10nA (max), the current in the dividers R1/R2 and R3/R4 (Figure 1) may be as low as 1 $\mu$ A without significantly affecting accuracy. Normally R2 and R4 are between 10k $\Omega$  and 1M $\Omega$ , which sets the current in the voltage-dividers in the 1.3 $\mu$ A to 130 $\mu$ A range. R1 and R3 can then be calculated as follows:

$$10\Omega \leq R2 \leq 1M\Omega \quad R1 = R2 \times \frac{V_{OUT} - 1.31V}{1.31}$$

$$10\Omega \leq R4 \leq 1M\Omega \quad R3 = R4 \times \frac{V_{LB} - 1.31V}{1.31}$$

where  $V_{OUT}$  is the desired output voltage and  $V_{LB}$  is the desired low-battery warning threshold.

If the  $I_C$  (shutdown) input is pulled up through a resistor rather than connected directly to  $+V_S$ , the current through the pullup resistor should be a minimum of 4 $\mu$ A with  $I_C$  at the input-high threshold of 1.3V:

$$R_{IC} \leq \frac{+V_S - 1.3V}{4\mu A}$$

### Inductor Value

The available output current from a DC-DC voltage boost converter is a function of the input voltage, external inductor value, output voltage, and the operating frequency.

The inductor must 1) have the correct inductance, 2) be able to handle the required peak currents, and 3) have acceptable series resistance and core losses. If the inductance is too high, the MAX630 will not be able to deliver the desired output power, even with the  $L_X$  output on for every oscillator cycle. The available output power can be increased by either decreasing the inductance or the frequency. Reducing the frequency increases the on-period of the  $L_X$  output, thereby increasing the peak inductor current. The available output power is increased since it is proportional to the square of the peak inductor current ( $I_{PK}$ ).

$$L = \frac{(V_{IN} T_{ON})^2 f}{2P_{OUT}}$$

since:  $P_{OUT} = \frac{L I_{PK}^2 f}{2}$

and:  $I_{PK} = \frac{V_{IN} T_{ON}}{L}$

where  $P_{OUT}$  includes the power dissipated in the catch

diode (D1) as well as that in the load. If the inductance is too low, the current at  $L_X$  may exceed the maximum rating. The minimum allowed inductor value is expressed by:

$$L_{MIN} = \frac{V_{IN} T_{ON}}{I_{MAX}}$$

where  $I_{MAX} \approx 525mA$  (peak  $L_X$  current) and  $t_{ON}$  is the on-time of the  $L_X$  output.

The most common MAX630 circuit is a boost-mode converter (Figure 1). When the N-channel output device is on, the current linearly rises since:

$$\frac{di}{dt} = \frac{V}{L}$$

At the end of the on-time (14 $\mu$ s for 40kHz, 55% duty-cycle oscillator) the current is:

$$I_{PK} = \frac{V T_{ON}}{L} = \frac{5V \times 14\mu s}{470\mu H} = 150mA$$

The energy in the coil is:

$$E = \frac{L I_{PK}^2}{2} = 5.25\mu J$$

At maximum load, this cycle is repeated 40,000 times per second, and the power transferred through the coil is 40,000  $\times$  5.25 = 210mW. Since the coil only supplies the voltage above the input voltage, at 15V, the DC-DC converter can supply 210mW / (15V - 5V) = 21mA. The coil provides 210mW and the battery directly supplies another 105mW, for a total of 315mW of output power. If the load draws less than 21mA, the MAX630 turns on its output only often enough to keep the output voltage at a constant 15V.

Reducing the inductor value increases the available output current: lower  $L$  increases the peak current, thereby increasing the available power. The external inductor required by the MAX630 is readily obtained from a variety of suppliers (Table 1). Standard coils are suitable for most applications.

### Types of Inductors

#### Molded Inductors

These are cylindrically wound coils that look similar to 1W resistors. They have the advantages of low cost and ease of handling, but have higher resistance, higher losses, and lower power handling capability than other types.

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## Potted Toroidal Inductors

A typical 1mH, 0.82 $\Omega$  potted toroidal inductor (Dale TE-3Q4TA) is 0.685in in diameter by 0.385in high and mounts directly onto a PC board by its leads. Such devices offer high efficiency and mounting ease, but at a somewhat higher cost than molded inductors.

## Ferrite Cores (Pot Cores)

Pot cores are very popular as switch-mode inductors since they offer high performance and ease of design. The coils are generally wound on a plastic bobbin, which is then placed between two pot core sections. A simple clip to hold the core sections together completes the inductor. Smaller pot cores mount directly onto PC boards through the bobbin terminals. Cores come in a wide variety of sizes, often with the center posts ground down to provide an air gap. The gap prevents saturation while accurately defining the inductance per turn squared.

Pot cores are suitable for all DC-DC converters, but are usually used in the higher power applications. They are also useful for experimentation since it is easy to wind coils onto the plastic bobbins.

## Toroidal Cores

In volume production, the toroidal core offers high performance, low size and weight, and low cost. They are, however, slightly more difficult for prototyping, in that manually winding turns onto a toroid is more tedious than on the plastic bobbins used with pot cores.

Toroids are more efficient for a given size since the flux is more evenly distributed than in a pot core, where the effective core area differs between the post, side, top, and bottom.

Since it is difficult to gap a toroid, manufacturers produce toroids using a mixture of ferromagnetic powder (typically iron or Mo-Permalloy powder) and a binder. The permeability is controlled by varying the amount of binder, which changes the effective gap between the ferromagnetic particles. Mo-Permalloy powder (MPP) cores have lower losses and are recommended for the highest efficiency, while iron powder cores are lower cost.

## Diodes

In most MAX630 circuits, the inductor current returns to zero before  $L_X$  turns on for the next output pulse. This allows the use of slow turn-off diodes. On the other hand, the diode current abruptly goes from zero to full peak current each time  $L_X$  switches off (Figure 1, D1). To avoid excessive losses, the diode must therefore have a fast turn-on time.

For low-power circuits with peak currents less than 100mA, signal diodes such as 1N4148s perform well. For higher-current circuits, or for maximum efficiency at low power, the 1N5817 series of Schottky diodes are recommended. Although 1N4001s and other general-purpose rectifiers are rated for high currents, they are unacceptable because their slow turn-on time results in excessive losses.

**Table 1. Coil and Core Manufacturers**

MANUFACTURER	TYPICAL PART NUMBER	DESCRIPTION
<b>MOLDED INDUCTORS</b>		
Dale	IHA-104	500 $\mu$ H, 0.5 $\Omega$
Nytronics	WEE-470	470 $\mu$ H, 10 $\Omega$
TRW	LL-500	500 $\mu$ H, 0.75 $\Omega$
<b>POTTED TOROIDAL INDUCTORS</b>		
Dale	TE-3Q4TA	1mH, 0.82 $\Omega$
TRW	MH-1	600 $\mu$ H, 1.9 $\Omega$
Torotel Prod.	PT 53-18	500 $\mu$ H, 5 $\Omega$
<b>FERRITE CORES AND TOROIDS</b>		
Allen Bradley	T0451S100A	Tor. core, 500nH/T <sup>2</sup>
Siemens	B64290-K38-X38	Tor. core, 4 $\mu$ H/T <sup>2</sup>
Magnetics	555130	Tor. core, 53nH/T <sup>2</sup>
Stackpole	57-3215	Pot core, 14mm x 18mm
Magnetics	G-41408-25	Pot core, 14 x 8, 250nH/T <sup>2</sup>

**Note:** This list does not constitute an endorsement by Maxim Integrated Products and is not intended to be a comprehensive list of all manufacturers of these components.



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## Filter Capacitor

The output-voltage ripple has two components, with approximately 90 degrees phase difference between them. One component is created by the change in the capacitor's stored charge with each output pulse. The other ripple component is the product of the capacitor's charge/discharge current and its effective series resistance (ESR). With low-cost aluminum electrolytic capacitors, the ESR-produced ripple is generally larger than that caused by the change in charge.

$$V_{\text{ESR}} = I_{\text{PK}} \times \text{ESR} = \left( \frac{V_{\text{IN}}}{2Lf} \right) \times \text{ESR} (\text{Volts-p-p})$$

where  $V_{\text{IN}}$  is the coil input voltage,  $L$  is its inductance,  $f$  is the oscillator frequency, and ESR is the equivalent series resistance of the filter capacitor.

The output ripple resulting from the change in charge on the filter capacitor is:

$$V_{\text{dQ}} = \frac{Q}{C} \text{ where, } Q = t_{\text{DIS}} \times \frac{I_{\text{PEAK}}}{2}$$

$$\text{and, } I_{\text{PEAK}} = t_{\text{CHG}} \times \frac{V_{\text{IN}}}{L}$$

$$V_{\text{dQ}} = \frac{V_{\text{IN}}(t_{\text{CHG}})(t_{\text{DIS}})}{2LC}$$

where  $t_{\text{CHG}}$  and  $t_{\text{DIS}}$  are the charge and discharge times for the inductor ( $1/2f$  can be used for nominal calculations).

## Oscillator Capacitor, $C_X$

The oscillator capacitor,  $C_X$ , is a noncritical ceramic or silver mica capacitor.  $C_X$  can also be calculated by:

$$C_X = \frac{2.14 \times 10^{-6}}{f} - C_{\text{INT}} \quad (C_{\text{INT}} \cong 5\text{pF, see text})$$

where  $f$  is the desired operating frequency in Hertz, and  $C_{\text{INT}}$  is the sum of the stray capacitance on the  $C_X$  pin and the internal capacitance of the package. The internal capacitance is typically 1pF for the plastic package and 3pF for the Cerdip package. Typical stray capacitances are about 3pF for normal PC board layouts, but will be significantly higher if a socket is used.

## Bypassing and Compensation

Since the inductor-charging current can be relatively large, high currents can flow through the ground connection of the MAX630/MAX4193. To prevent unwanted feedback, the impedance of the ground path must be as low as possible, and supply bypassing should be used for the device.

When large values ( $>50\text{k}\Omega$ ) are used for the voltage-setting resistors,  $R_1$  and  $R_2$  of Figure 1, stray capacitance at the  $V_{\text{FB}}$  input can add a lag to the feedback response, destabilizing the regulator, increasing low-frequency ripple, and lowering efficiency. This can often be avoided by minimizing the stray capacitance at the  $V_{\text{FB}}$  node. It can also be remedied by adding a lead compensation capacitor of 100pF to 10nF in parallel with  $R_1$  in Figure 1.

## DC-DC Converter Configurations

DC-DC converters come in three basic topologies: buck, boost, and buck-boost (Figure 2). The MAX630 is usually operated in the positive-voltage boost circuit, where the output voltage is greater than the input.

The boost circuit is used where the input voltage is always less than the desired output and the buck circuit is used where the input is greater than the output. The buck-boost circuit inverts, and can be used with, input

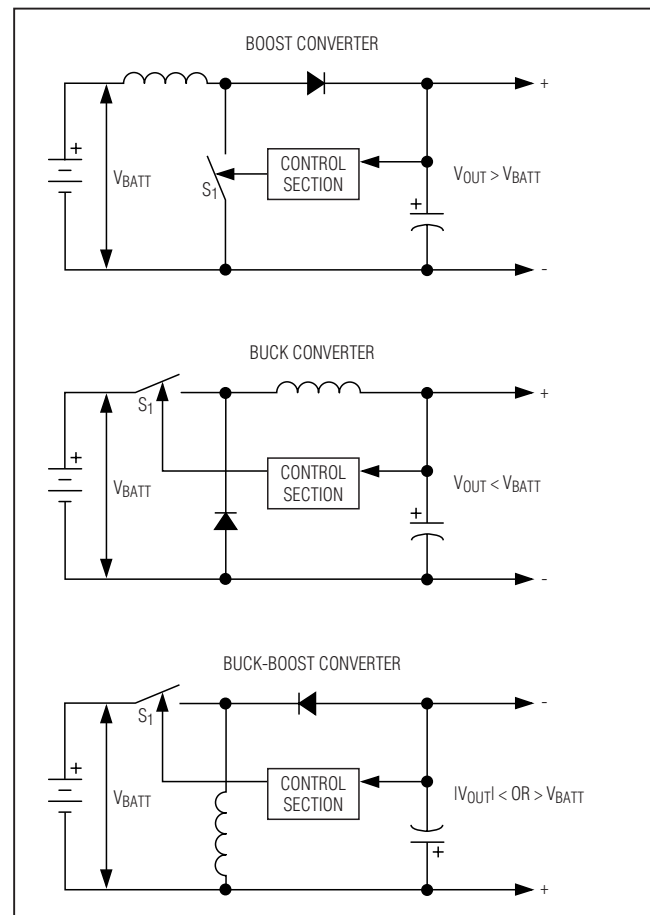


Figure 2. DC-DC Converter Configurations

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voltages that are either greater or less than the output.

DC-DC converters can also be classified by the control method. The two most common are pulse-width modulation (PWM) and pulse-frequency modulation (PFM). PWM switch-mode power-supply ICs (of which current-mode control is one variant) are well-established in high-power off-line switchers. Both PWM and PFM circuits control the output voltage by varying duty cycle. In the PWM circuit, the frequency is held constant and the width of each pulse is varied. In the PFM circuit, the pulse width is held constant and duty cycle is controlled by changing the pulse repetition rate.

The MAX630 refines the basic PFM by employing a constant-frequency oscillator. Its output MOSFET is switched on when the oscillator is high and the output voltages is lower than desired. If the output voltage is higher than desired, the MOSFET output is disabled for that oscillator cycle. This pulse skipping varies the average duty cycle, and thereby controls the output voltage.

Note that, unlike the PWM ICs, which use an op amp as the control element, the MAX630 uses a comparator to compare the output voltage to an onboard reference. This reduces the number of external components and operating current.

## Typical Applications

### **+5V to +15V DC-DC Converter**

Figure 1 shows a simple circuit that generates +15V at approximately 20mA from a +5V input. The MAX630 has a  $\pm 1.5\%$  reference accuracy, so the output voltage has an untrimmed accuracy of  $\pm 3.5\%$  if R1 and R2 are 1% resistors. Other output voltages can also be selected by changing the feedback resistors. Capacitor Cx sets the oscillator frequency ( $47\text{pF} = 40\text{kHz}$ ), while C1 limits output ripple to about 50mV.

With a low-cost molded inductor, the circuit's efficiency is about 75%, but an inductor with lower series resistance such as the Dale TE3Q4TA increases efficiency to around 85%. A key to high efficiency is that the MAX630 itself is powered from the +15V output. This provides the onboard N-channel output device with 15V gate drive, lowering its on-resistance to about 4 $\Omega$ . When +5V power is first applied, current flows through L1 and D1, supplying the MAX630 with 4.4V for startup.

### **+5V to $\pm 15V$ DC-DC Converter**

The circuit in Figure 3 is similar to that of Figure 1 except that two more windings are added to the inductor. The 1408 (14mm x 8mm) pot core specified is an IEC standard size available from many manufacturers (see Table 1). The -15V output is semiregulated, typi-

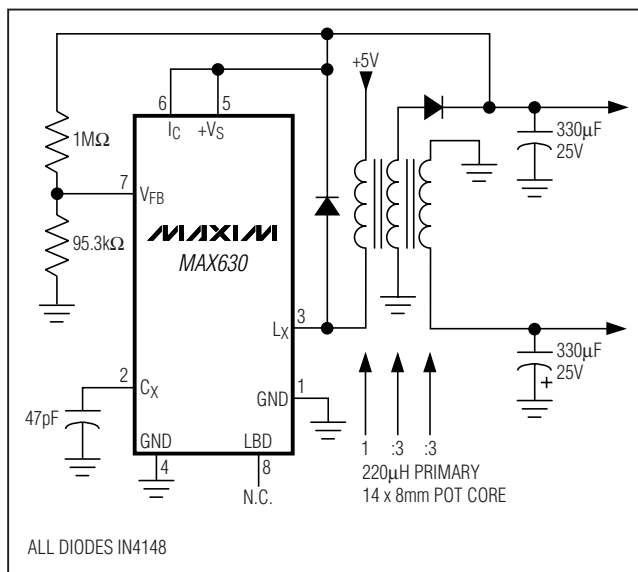


Figure 3. +5V to  $\pm 15V$  Converter

cally varying from -13.6V to -14.4V as the +15V load current changes from no load to 20mA.

## 2.5W, 3V to 5V DC-DC Converter

Some systems, although battery powered, need high currents for short periods, and then shut down to a low-power state. The extra circuitry of Figure 4 is designed to meet these high-current needs. Operating in the buck-boost or flyback mode, the circuit converts -3V to +5V. The left side of Figure 4 is similar to Figure 1 and supplies 15V for the gate drive of the external power MOSFET. This 15V gate drive ensures that the external device is completely turned on and has low on-resistance.

The right side of Figure 4 is a -3V to +5V buck-boost converter. This circuit has the advantage that when the MAX630 is turned off, the output voltage falls to 0V, unlike the standard boost circuit, where the output voltage is  $V_{BATT} - 0.6V$  when the converter is shut down. When shut down, this circuit uses less than 10 $\mu A$ , with most of the current being the leakage current of the power MOSFET.

The inductor and output-filter capacitor values have been selected to accommodate the increased power levels. With the values indicated, this circuit can supply up to 500mA at 5V, with 85% efficiency. Since the left side of the circuit powers only the right-hand MAX630, the circuit starts up with battery voltages as low as 1.5V, independent of the loading on the +5V output.

# MAX630/MAX4193



# CMOS Micropower Step-Up Switching Regulator

### **+3V Battery to +5V DC-DC Converter**

A common power-supply requirement involves conversion of a 2.4V or 3V battery voltage to a 5V logic supply. The circuit in Figure 5 converts 3V to 5V at 40mA with 85% efficiency. When IC (pin 6) is driven low, the output voltage will be the battery voltage minus the drop across diode D1.

The optional circuitry using C1, R3, and R4 lowers the oscillator frequency when the battery voltage falls to 2.0V. This lower frequency maintains the output-power capability of the circuit by increasing the peak inductor current, compensating for the reduced battery voltage.

## Uninterruptable +5V Supply

In Figure 6, the MAX630 provides a continuous supply of regulated +5V, with automatic switchover between line power and battery backup. When the line-powered input voltage is at +5V, it provides 4.4V to the MAX630 and trickle charges the battery. If the line-powered input falls below the battery voltage, the 3.6V battery supplies power to the MAX630, which boosts the battery voltage up to +5V, thus maintaining a continuous supply to the uninterruptable +5V bus. Since the +5V output is always supplied through the MAX630, there are no power spikes or glitches during power transfer.

The MAX630's low-battery detector monitors the line-powered +5V, and the LBD output can be used to shut down unnecessary sections of the system during power failures. Alternatively, the low-battery detector could monitor the NiCad battery voltage and provide warning of power loss when the battery is nearly discharged.

Unlike battery backup systems that use 9V batteries, this circuit does not need +12V or +15V to recharge the battery. Consequently, it can be used to provide +5V backup on modules or circuit cards that only have 5V available.

## 9V Battery Life Extender

Figure 7's circuit provides a minimum of 7V until the 9V battery voltage falls to less than 2V. When the battery voltage is above 7V, the MAX630's  $I_C$  pin is low, putting it into the shutdown mode that draws only 10nA. When the battery voltage falls to 7V, the MAX8212 voltage detector's output goes high, enabling the MAX630. The MAX630 then maintains the output voltage at 7V, even as the battery voltage falls below 7V. The LBD is used to decrease the oscillator frequency when the battery voltage falls to 3V, thereby increasing the output current capability of the circuit.

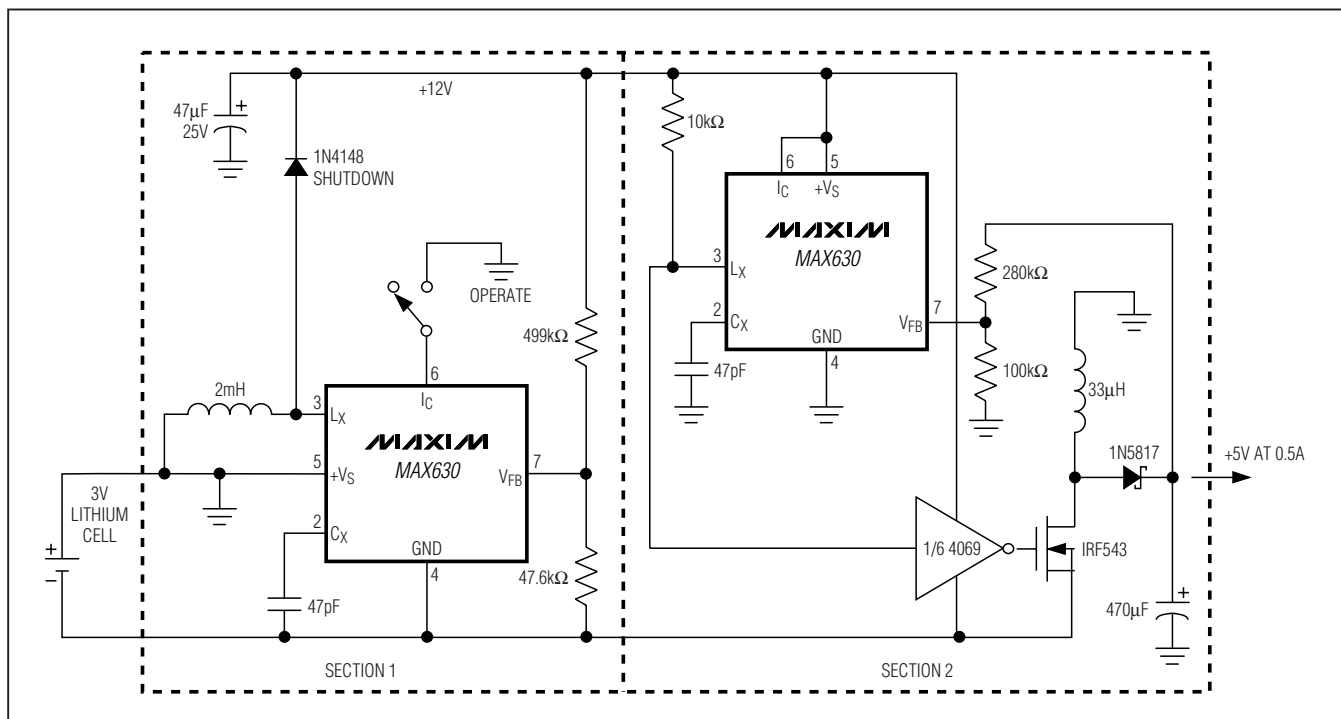


Figure 4. High-Power 3V to 5V Converter with Shutdown

# CMOS Micropower Step-Up Switching Regulator

Note that this circuit (with or without the MAX8212) can be used to provide 5V from four alkaline cells. The initial voltage is approximately 6V, and the output is maintained at 5V even when the battery voltage falls to less than 2V.

## Dual-Tracking Regulator

A MAX634 inverting regulator is combined with a MAX630 in Figure 8 to provide a dual-tracking  $\pm 15V$

output from a 9V battery. The reference for the -15V output is derived from the positive output through R3 and R4. Both regulators are set to maximize output power at low-battery voltage by reducing the oscillator frequency, through LBR, when  $V_{BATT}$  falls to 7.2V.

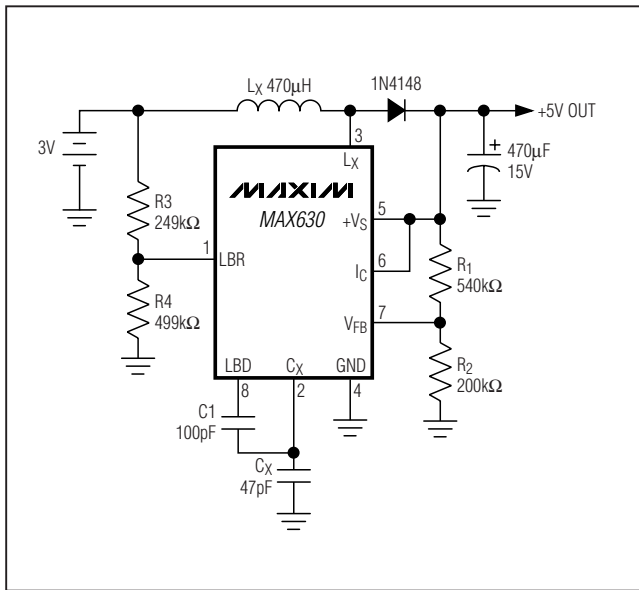


Figure 5. 3V to 5V Converter with Low-Battery Frequency Shift

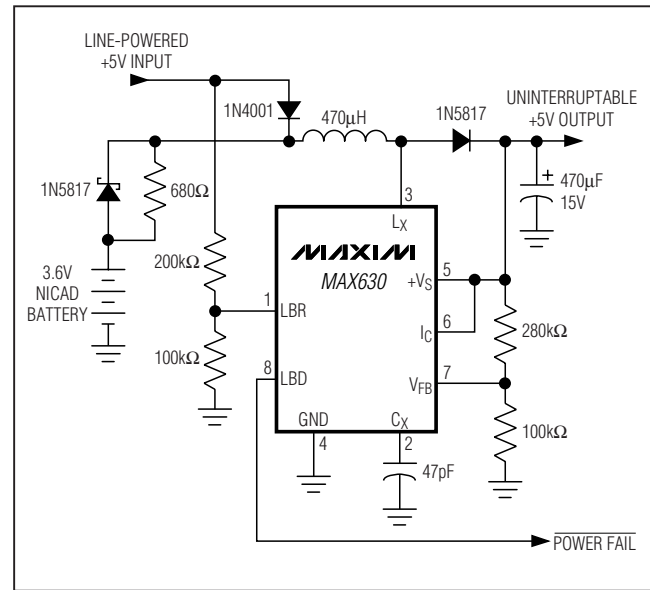


Figure 6. Uninterruptible +5V Supply

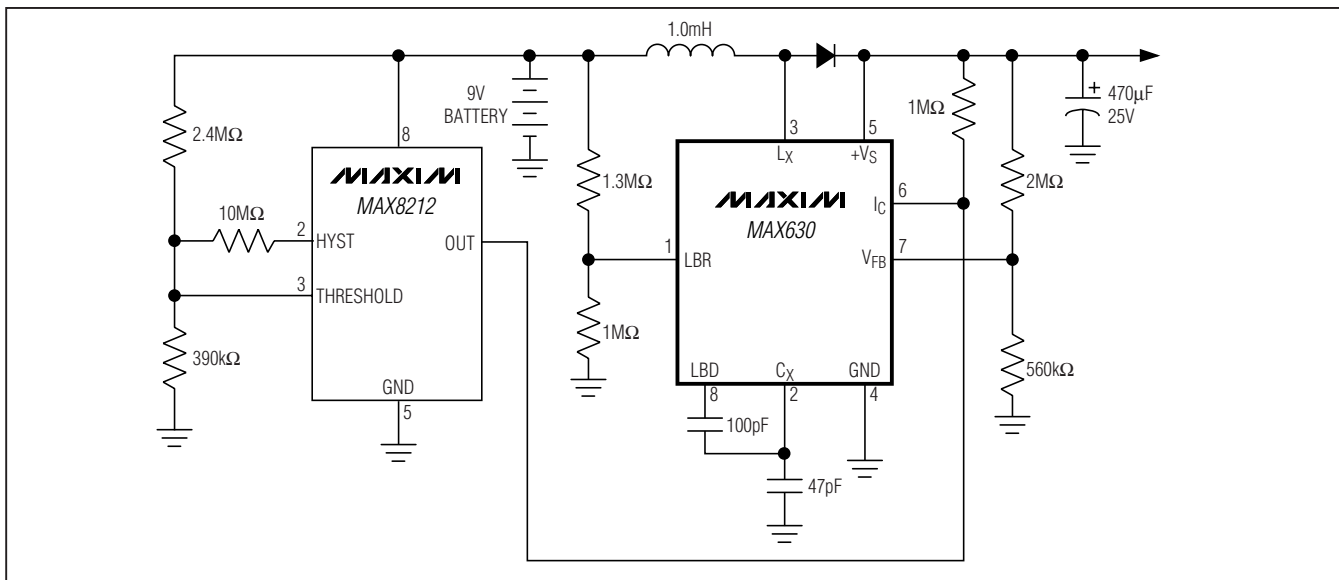


Figure 7. Battery Life Extension Down to 3V In

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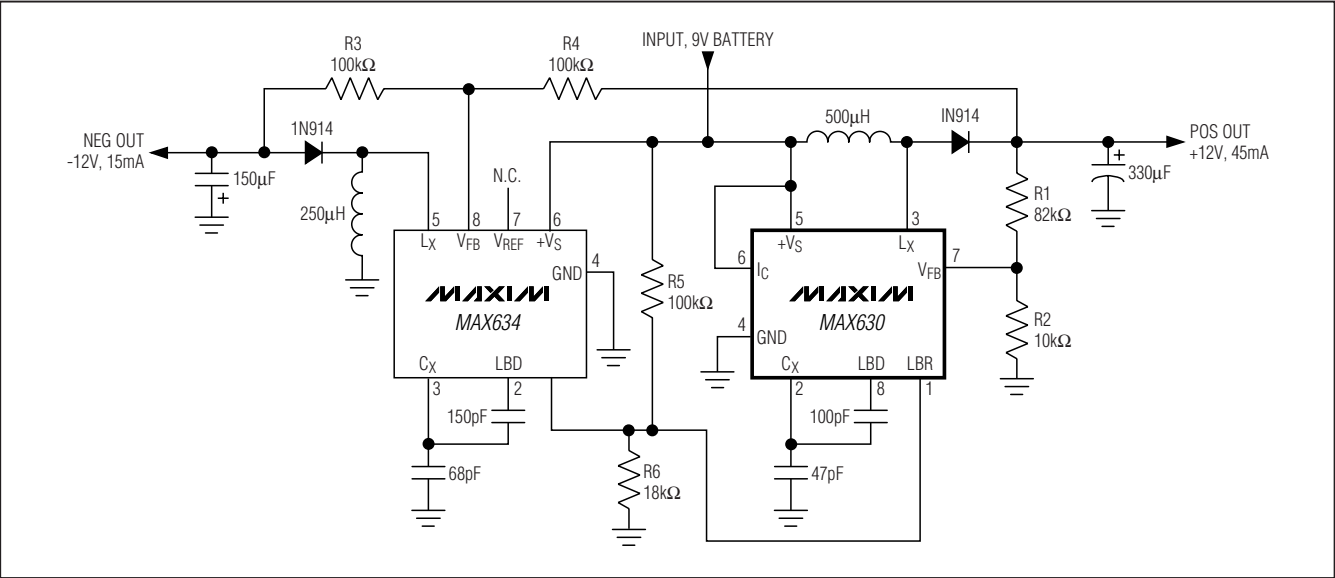


Figure 8. ±12V Dual-Tracking Regulator

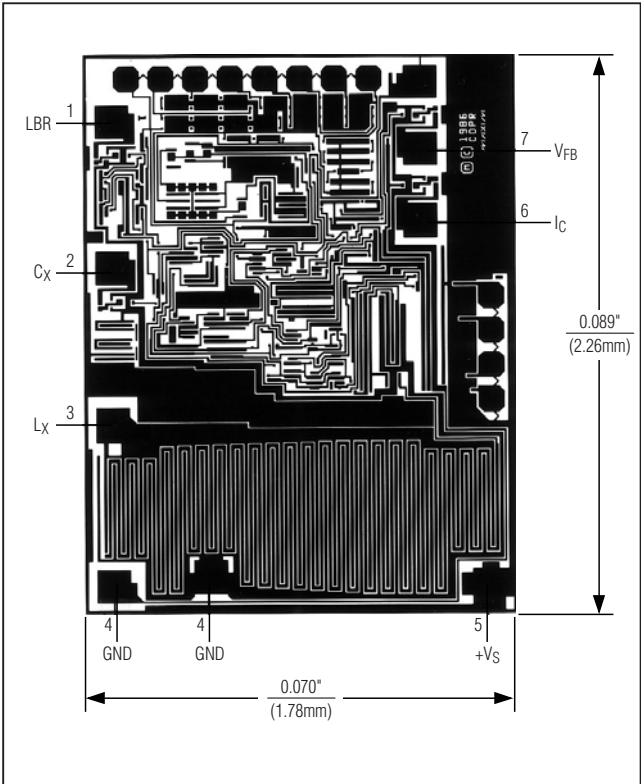
Table 2. Maxim DC-DC Converters

DEVICE	DESCRIPTION	INPUT VOLTAGE	OUTPUT VOLTAGE	COMMENTS
ICL7660	Charge-Pump Voltage Inverter	1.5V to 10V	-VIN	Not regulated
MAX4193	DC-DC Boost Converter	2.4V to 16.5V	VOUT > VIN	RC4193 2 <sup>nd</sup> source
MAX630	DC-DC Boost Converter	2.0V to 16.5V	VOUT > VIN	Improved RC4191 2 <sup>nd</sup> source
MAX631	DC-DC Boost Converter	1.5V to 5.6V	+5V	Only 2 external components
MAX632	DC-DC Boost Converter	1.5V to 12.6V	+12V	Only 2 external components
MAX633	DC-DC Boost Converter	1.5V to 15.6V	+15V	Only 2 external components
MAX4391	DC-DC Voltage Inverter	4V to 16.5V	Up to -20V	RC4391 2 <sup>nd</sup> source
MAX634	DC-DC Voltage Inverter	2.3V to 16.5V	Up to -20V	Improved RC4391 2 <sup>nd</sup> source
MAX635	DC-DC Voltage Inverter	2.3V to 16.5V	-5V	Only 3 external components
MAX636	DC-DC Voltage Inverter	2.3V to 16.5V	-12V	Only 3 external components
MAX637	DC-DC Voltage Inverter	2.3V to 16.5V	-15V	Only 3 external components
MAX638	DC-DC Voltage Step-Down	3V to 16.5V	VOUT < VIN	Only 3 external components
MAX641	High-Power Boost Converter	1.5V to 5.6V	+5V	Drives external MOSFET
MAX642	High-Power Boost Converter	1.5V to 12.6V	+12V	Drives external MOSFET
MAX643	High-Power Boost Converter	1.5V to 15.6V	+15V	Drives external MOSFET

# CMOS Micropower Step-Up Switching Regulator

MAX630/MAX4193

## Chip Topography



## Package Information

For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
8 PDIP	P8-T	<a href="#">21-0043</a>
8 SO	S8-4	<a href="#">21-0041</a>
8 CERDIP	J8-2	<a href="#">21-0045</a>

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## Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
2	9/08	Added information for rugged plastic product	1

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